NSN 5961-00-481-5517

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-481-5517 **Inclosure Material:** Glass and metal **Overall Length:** 0.190 inches **Overall Diameter:** 0.650 inches **End Application:** An/aqa- (v) **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 50.0 reverse voltage, peak **Current Rating Per Characteristic:** 10.00 milliamperes forward current, average major **Power Rating Per Characteristic:** 2.5 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig:

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